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November 2013

## FDD5N60NZ

# N-Channel UniFET<sup>TM</sup> II MOSFET 600 V, 4.0 A, 2 $\Omega$

### **Features**

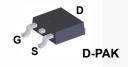
- $R_{DS(on)}$  = 1.65  $\Omega$  (Typ.) @  $V_{GS}$  = 10 V,  $I_D$  = 2.0 A
- Low Gate Charge (Typ. 10 nC)
- Low C<sub>rss</sub> (Typ. 5 pF)
- 100% Avalanche Tested
- · Improved dv/dt Capability
- · ESD Imoroved Capability
- · RoHS Compliant

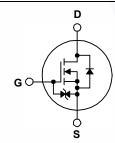
## **Applications**

- LCD/LED/PDP TV
- · Lighting
- · Uninterruptible Power Supply

## Description

UniFET<sup>TM</sup> II MOSFET is Fairchild Semiconductor's high voltage MOSFET family based on advanced planar stripe and DMOS technology. This advanced MOSFET family has the smallest on-state resistance among the planar MOSFET, and also provides superior switching performance and higher avalanche energy strength. In addition, internal gate-source ESD diode allows UniFET<sup>TM</sup> II MOSFET to withstand over 2kV HBM surge stress. This device family is suitable for switching power converter applications such as power factor correction (PFC), flat panel display (FPD) TV power, ATX and electronic lamp ballasts





## MOSFET Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted.

Symbol		Parameter		FDD5N60NZ	Unit
V <sub>DSS</sub>	Drain to Source Voltage		7	600	V
V <sub>GSS</sub>	Gate to Source Voltage			±25	V
	Drain Current	- Continuous (T <sub>C</sub> = 25°C)		4.0	
'D	Drain Current	- Continuous (T <sub>C</sub> = 100°C)		2.4	A
I <sub>DM</sub>	Drain Current	- Pulsed	(Note 1)	16	Α
E <sub>AS</sub>	Single Pulsed Avalanche Energy	,	(Note 2)	216	mJ
I <sub>AR</sub>	Avalanche Current		(Note 1)	4.0	Α
E <sub>AR</sub>	Repetitive Avalanche Energy (Note 1)		8.3	mJ	
dv/dt	Peak Diode Recovery dv/dt		(Note 3)	10	V/ns
D	Davier Discipation	$(T_C = 25^{\circ}C)$		83	W
$P_{D}$	Power Dissipation	- Derate Above 25°C		0.7	W/°C
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range		-55 to +150	οС	
T <sub>I</sub>	Maximum Lead Temperature for	Soldering, 1/8" from Case for 5 Se	econds	300	٥С

## **Thermal Characteristics**

Symbol	Parameter FDD5N60NZ		Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	1.5	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient, Max. 90		-C/VV

## **Package Marking and Ordering Information**

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FDD5N60NZTM	FDD5N60NZ	DPAK	Tape and Reel	330 mm	16 mm	2500 units

## **Electrical Characteristics** T<sub>C</sub> = 25°C unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Charac	cteristics					
BV <sub>DSS</sub>	Drain to Source Breakdown Voltage	$I_D = 250 \mu A, V_{GS} = 0 V, T_J = 25^{\circ} C$	600	-	-	V
ΔBV <sub>DSS</sub> / ΔT <sub>J</sub>	Breakdown Voltage Temperature Coefficient	$I_D$ = 250 $\mu$ A, Referenced to 25°C	-	0.6	-	V/°C
1	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 600 V, V <sub>GS</sub> = 0 V	-	-	50	
DSS	Zero Gate voltage Drain Current	$V_{DS} = 480 \text{ V}, T_{C} = 125^{\circ}\text{C}$	-	-	100	μА
I <sub>GSS</sub>	Gate to Body Leakage Current	$V_{GS} = \pm 25 \text{ V}, V_{DS} = 0 \text{ V}$	-	-	±10	μΑ

## **On Characteristics**

V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$	3.0	-	5.0	V
R <sub>DS(on)</sub>	Static Drain to Source On Resistance	$V_{GS} = 10 \text{ V}, I_D = 2.0 \text{ A}$	-	1.65	2.00	Ω
9 <sub>FS</sub>	Forward Transconductance	V <sub>DS</sub> = 20 V, I <sub>D</sub> = 2.0 A	-	5	-	S

## **Dynamic Characteristics**

C <sub>iss</sub>	Input Capacitance	V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 0 V, f = 1 MHz		-	450	600	pF
C <sub>oss</sub>	Output Capacitance			-	50	65	pF
C <sub>rss</sub>	Reverse Transfer Capacitance	1 - 1 101112	-	-\	5	7.5	pF
Q <sub>g(tot)</sub>	Total Gate Charge at 10V			- \	10	13	nC
$Q_{gs}$	Gate to Source Gate Charge	$V_{DS} = 400 \text{ V}, I_{D} = 4.0 \text{ A},$	-	-	2.5	-	nC
Q <sub>gd</sub>	Gate to Drain "Miller" Charge	V <sub>GS</sub> = 10 V	(Note 4)	-	4	-	nC

## **Switching Characteristics**

	_						
t <sub>d(on)</sub>	Turn-On Delay Time			-	15	40	ns
t <sub>r</sub>	Turn-On Rise Time	$V_{DD} = 250 \text{ V}, I_D = 4.0 \text{ A},$		-	20	50	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	$V_{GS}$ = 10 V, $R_G$ = 25 $\Omega$		- /	35	80	ns
t <sub>f</sub>	Turn-Off Fall Time		(Note 4)	- /	20	50	ns

## **Drain-Source Diode Characteristics**

Is	Maximum Continuous Drain to Source Diod	Maximum Continuous Drain to Source Diode Forward Current		-	4.0	Α
I <sub>SM</sub>	Maximum Pulsed Drain to Source Diode Fo	Maximum Pulsed Drain to Source Diode Forward Current		-	16	Α
$V_{SD}$	Drain to Source Diode Forward Voltage	V <sub>GS</sub> = 0 V, I <sub>SD</sub> = 4.0 A	-	-	1.4	V
t <sub>rr</sub>	Reverse Recovery Time	V <sub>GS</sub> = 0 V, I <sub>SD</sub> = 4.0 A,	-	230	-	ns
Q <sub>rr</sub>	Reverse Recovery Charge	$dI_F/dt = 100 A/\mu s$	-	0.9	-	μС

#### Notes

- ${\it 1. Repetitive\ rating: pulse-width\ limited\ by\ maximum\ junction\ temperature.}$
- 2. L = 27 mH, I $_{AS}$  = 4.0 A, V $_{DD}$  = 50 V, R $_{G}$  = 25  $\Omega$ , starting T $_{J}$  = 25°C.
- 3.  $I_{SD} \le 4.0$  A, di/dt  $\le 200$  A/ $\mu$ s,  $V_{DD} \le BV_{DSS}$ , starting  $T_J = 25$ °C.
- Essentially independent of operating temperature typical characteristics.

## **Typical Performance Characteristics**

Figure 1. On-Region Characteristics

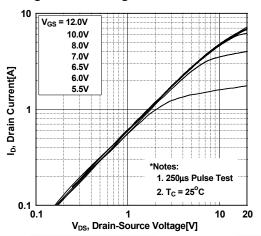
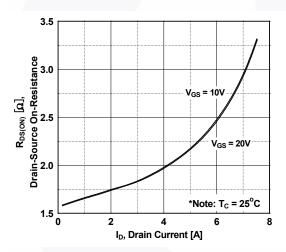


Figure 3. On-Resistance Variation vs.

Drain Current and Gate Voltage



**Figure 5. Capacitance Characteristics** 

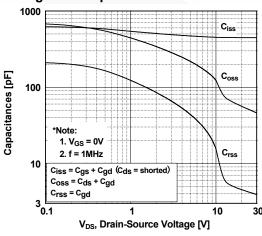


Figure 2. Transfer Characteristics

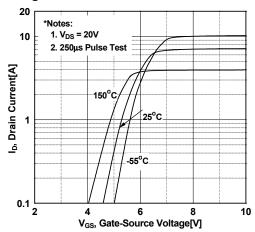


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

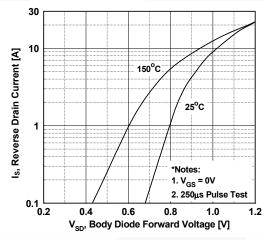
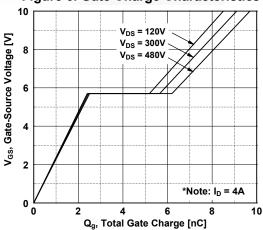


Figure 6. Gate Charge Characteristics



## **Typical Performance Characteristics** (Continued)

Figure 7. Breakdown Voltage Variation vs. Temperature

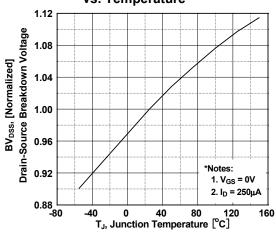


Figure 8. On-Resistance Variation vs. Temperature

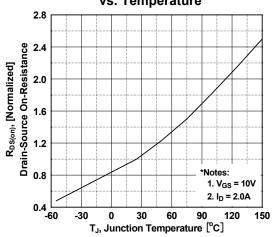


Figure 9. Maximum Safe Operating Area

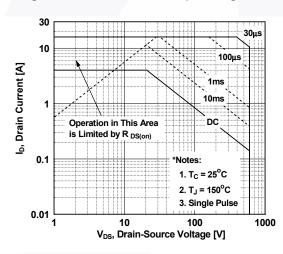


Figure 10. Maximum Drain Current vs. Case Temperature

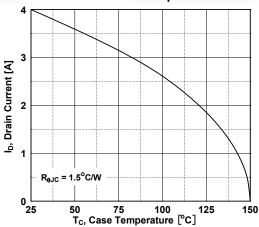
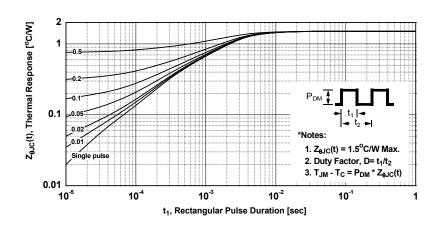


Figure 11. Transient Thermal Response Curve



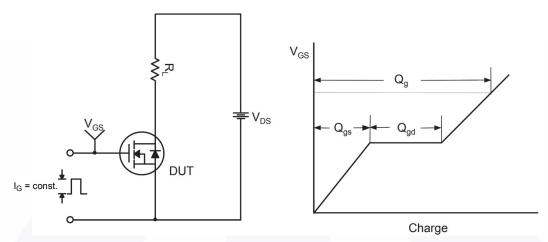


Figure 12. Gate Charge Test Circuit & Waveform

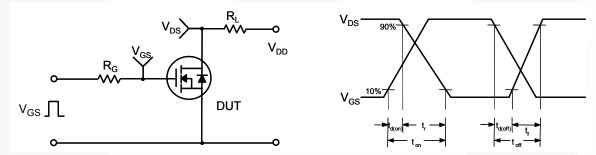


Figure 13. Resistive Switching Test Circuit & Waveforms

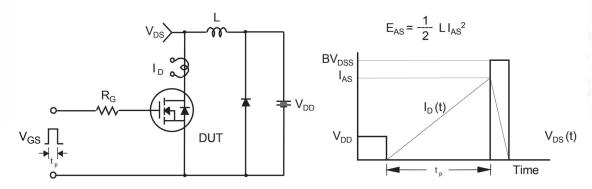


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms

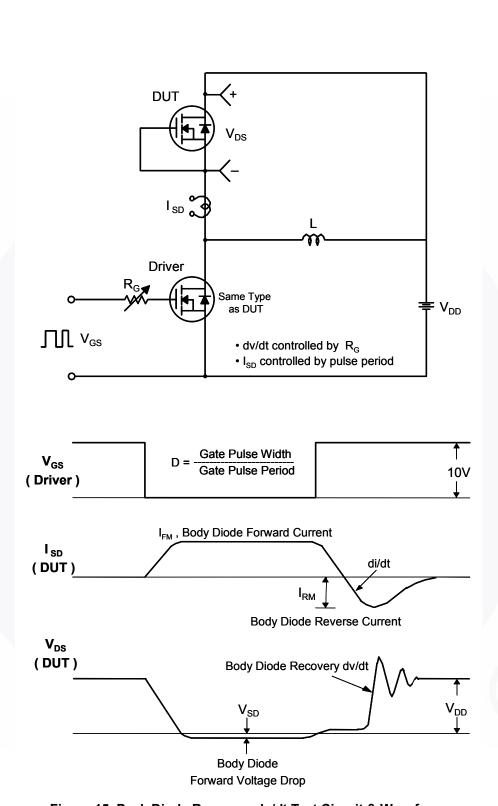


Figure 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms

## **Mechanical Dimensions**

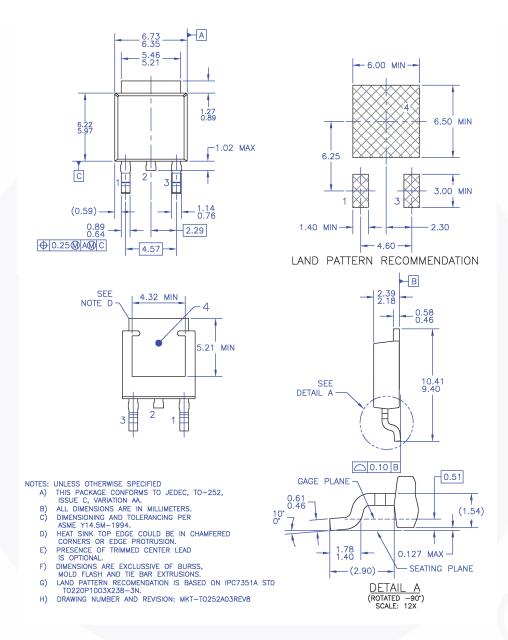


Figure 16. TO252 (D-PAK), Molded, 3-Lead, Option AA&AB

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